# Property of Lite-On Only

### **FEATURES**

- \*0.3 inch (7.62 mm) DIGIT HEIGHT
- **\*EXCELLENT SEGMENT UNIFORMITY**
- **\*LOW POWER REQUIREMENT**
- \*HIGH BRIGHTNESS AND HIGH CONTRAST
- \*WIDE VIEWING ANGLE
- **\* SOLID STATE RELIABILITY**
- \*BINNED FOR LUMINOUS INTENSITY

### **DESCRIPTION**

The LSHD-7503 is a 0.3 inch (7.62 mm) digit height single-digit display. This device uses AS-AlInGaP RED LED chips (AlInGaP epi on GaAs substrate). The display has light gray face and white segments.

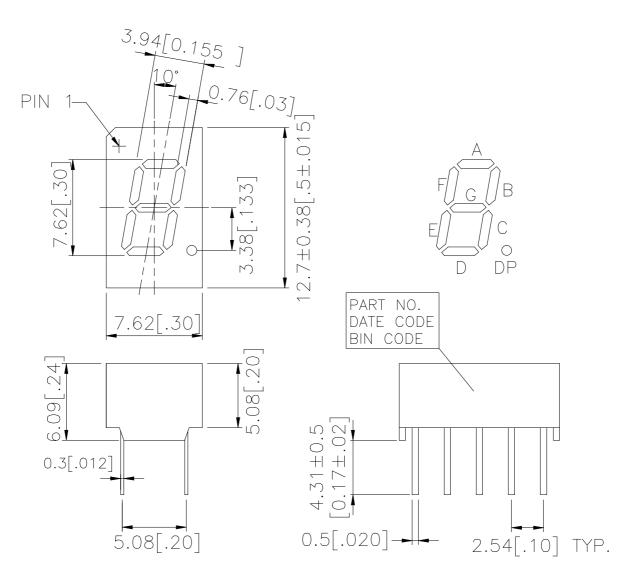
### **DEVICE**

PART NO.	DESCRIPTION			
AlInGaP RED	Common Cathode			
LSHD-7503	Rt. Hande Decimal			

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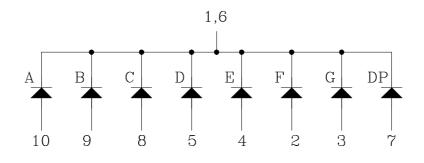
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## **PACKAGE DIMENSIONS**



NOTES: All dimensions are in millimeters. Tolerances are  $\pm$  0.25mm (0.01") unless otherwise noted.

## INTERNAL CIRCUIT DIAGRAM



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## **PIN CONNECTION**

No.	CONNECTION
1	Common Cathode
2	Anode F
3	Anode G
4	Anode E
5	Anode D
6	Common Cathode
7	Anode DP
8	Anode C
9	Anode B
10	Anode A

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## ABSOLUTE MAXIMUM RATING AT $Ta = 25^{\circ}C$

PARAMETER	MAXIMUM RATING	UNIT				
Power Dissipation Per Segment	70	mW				
Peak Forward Current Per Segment (Frequency 1Khz, 15% duty cycle)	90	mA				
Continuous Forward Current Per Segment	25	mA				
Forward Current Derating from 25 <sup>o</sup> C	0.28	mA/ <sup>0</sup> C				
Reverse Voltage Per Segment	5	V				
Operating Temperature Range	$-35^{\circ}$ C to $+105^{\circ}$ C					
Storage Temperature Range -35°C to +105°C						
Soldering Conditions: 1/16 inch below seating plane for 3 seconds at 260 <sup>o</sup> C						

# ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta = 25°C

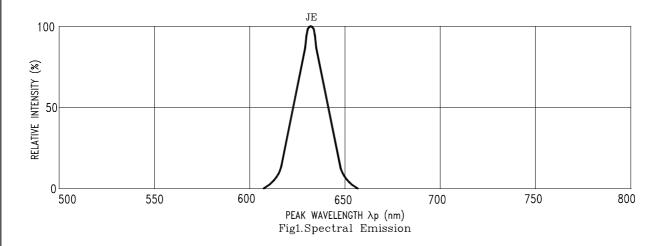
PARAMETER	SYMBOL	MIN	ТҮР	MAX	UNIT	TEST CONDITION
Average Luminous Intensity Per Segment	Iv	320	923		μcd	$I_F = 1 \text{mA}$
		5400	12000			$I_F = 10 \text{mA}$
Peak Emission Wavelength	λр		632		nm	$I_F = 20 \text{mA}$
Spectral Line Half-Width	Δλ		20		nm	$I_F = 20 \text{mA}$
Dominant Wavelength	λd		624		nm	$I_F = 20 \text{mA}$
Forward Voltage Per Segment	VF		2.1	2.6	V	$I_F = 20 \text{mA}$
Reverse Current Per Segment	Ir			100	μΑ	$V_R = 5V$
Luminous Intensity Matching Ratio	Iv-m			2:1		$I_F = 1mA$

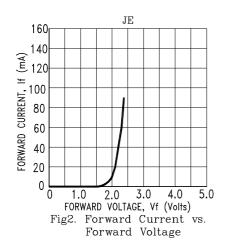
Note: Luminous Intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

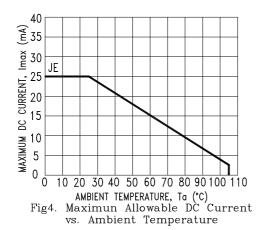
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### TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

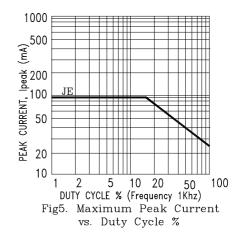






JΕ 10 15 20 FORWARD CURRENT, If (mA) Fig3. Relative Luminous Intensity

vs. DC Forward Current



NOTE: JE=AlInGaP RED

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